



20V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| BV _{DSS} | R _{DS(ON) MAX} | Package | I_{D} $T_{A} = +25^{\circ}C$ |
|-------------------|-------------------------------|-------------------------|--------------------------------|
| | 11mΩ @ V _{GS} = 4.5V | U-DFN2020-6 (Type E) | 10.5A |
| 20V | 13mΩ @ V _{GS} = 2.5V | U-DFN2020-6 (Type E) | 9.4A |
| 200 | 30mΩ @ V _{GS} = 1.8V | U-DFN2020-6 (Type E) | 6.5A |
| | 50mΩ @ V _{GS} = 1.5V | U-DFN2020-6 (Type E) | 5.5A |

Description

This new generation MOSFET has been designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- Power Management Functions

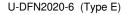
Features

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/
 - An Automative Compliant Part is Available Under Co
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMN2013UFDEQ</u>)

Mechanical Data

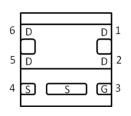
- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0065 grams (Approximate)



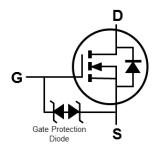




Bottom View



Pin Out



Equivalent Circuit

Ordering Information (Note 4)

| Part Number | Compliance | Case | Quantity per Reel |
|----------------|------------|----------------------|-------------------|
| DMN2013UFDE-7 | Standard | U-DFN2020-6 (Type E) | 3,000 |
| DMN2013UFDE-13 | Standard | U-DFN2020-6 (Type E) | 10,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1



N6 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

| Year | 2012 | ••• | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 |
|-------|------|-----|------|------|------|------|------|------|------|------|------|------|
| Code | Z | | | J | K | L | М | N | 0 | Р | R | S |
| | | | | | | | | | | | | |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |

Site 2



N6 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 1 = 2021)

W = Week (ex: a = week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

| Year | 2012 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 |
|------|------|----------|------|------|------|------|------|------|------|------|------|
| Code | 2 | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 |

| Week | 1-26 | 27-52 | 53 |
|------|------|-------|----|
| Code | A-Z | a-z | Z |

| Internal Code | Sun | Mon | Tue | Wed | Thu | Fri | Sat |
|---------------|-----|-----|-----|-----|-----|-----|-----|
| Code | T | U | V | W | X | Υ | Z |



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|--|---|--|------------------|--------------|---|
| Drain-Source Voltage | | | V _{DSS} | 20 | V |
| Gate-Source Voltage | | | V_{GSS} | ±8 | V |
| Continuous Drain Current (Note 6) V 45V | Steady $T_A = +25$ °C $T_A = +70$ °C | | l _D | 10.5 8.5 | Α |
| Continuous Drain Current (Note 6) V _{GS} = 4.5V | t < 10s | T _A = +25°C T _A = +70°C | l _D | 12.5 10.0 | Α |
| Continuous Dunin Comment (Note C) V O. F.V. | Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$ | | | 9.4 7.5 | Α |
| Continuous Drain Current (Note 6) VGS = 2.5V $t < 10s$ $T_A = +25^{\circ}$ $T_A = +70^{\circ}$ | | | I _D | 11.2 8.8 | Α |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1% | IDM | 80 | Α | | |
| Maximum Body Diode Continuous Current | | | Is | 2.5 | A |

Thermal Characteristics

| Characteristic | Characteristic | | | Unit | |
|--|----------------------|-------------------|-------------|------|--|
| Total Power Discinction (Note 5) | $T_A = +25^{\circ}C$ | Pp | 0.66 | W | |
| Total Power Dissipation (Note 5) | $T_A = +70$ °C | PD | 0.42 | VV | |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | D | 189 | °C/W | |
| Thermal Resistance, Junction to Ambient (Note 3) | t<10s | R _θ JA | 132 | C/VV | |
| Total Power Dissipation (Note 6) | $T_A = +25^{\circ}C$ | Pn | 2.03 | W | |
| Total Fower Dissipation (Note 6) | $T_A = +70^{\circ}C$ | FD | 1.31 | VV | |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State | р | 61 | | |
| memai hesistance, sunction to Ambient (Note 6) | t<10s | $R_{\theta JA}$ | 43 | °C/W | |
| Thermal Resistance, Junction to Case (Note 6) | Rejc | 9.3 | | | |
| Operating and Storage Temperature Range | | $T_{J,}T_{STG}$ | -55 to +150 | °C | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|-------|-----|-------|--|--|
| OFF CHARACTERISTICS (Note 7) | | | - / . | | I. | 1 | |
| Drain-Source Breakdown Voltage | BVDSS | 20 | _ | _ | V | V _G S = 0V, I _D = 250µA | |
| Zero Gate Voltage Drain Current T _J = +25°C | IDSS | _ | _ | 1 | μΑ | V _{DS} = 16V, V _{GS} = 0V | |
| Gate-Source Leakage | Igss | _ | _ | ±2 | μΑ | $V_{GS} = \pm 8V$, $V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | • | • | |
| Gate Threshold Voltage | V _{GS(TH)} | 0.5 | 1 | 1.1 | V | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | |
| | | | 8.4 | 11 | | $V_{GS} = 4.5V, I_D = 8.5A$ | |
| Static Drain-Source On-Resistance | D | | 9.8 | 13 | mΩ | $V_{GS} = 2.5V, I_{D} = 8.5A$ | |
| Static Drain-Source On-Nesistance | RDS(ON) | _ | 12 | 30 | 11122 | $V_{GS} = 1.8V, I_D = 1A$ | |
| | | | 15 | 50 | | V _{GS} = 1.5V, I _D = 0.5A | |
| Forward Transfer Admittance | Y _{fs} | _ | 10 | _ | S | V _{DS} = 5V, I _D = 4A | |
| Diode Forward Voltage | V _{SD} | _ | _ | 1.2 | V | $V_{GS} = 0V, I_S = 8.5A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | Ciss | | 2453 | _ | pF | | |
| Output Capacitance | Coss | | 275 | 1 | рF | V _{DS} = 10V, V _{GS} = 0V, - f = 1.0MHz | |
| Reverse Transfer Capacitance | Crss | | 257 | _ | pF | T = T.OIVII IZ | |
| Gate Resistance | R_g | - | 1.2 | _ | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | | 14.3 | _ | nC | | |
| Total Gate Charge (V _{GS} = 8V) | Qg | | 25.8 | _ | nC | V 10V I 0.5A | |
| Gate-Source Charge | Qgs | _ | 1.8 | _ | nC | $V_{DS} = 10V, I_D = 8.5A$ | |
| Gate-Drain Charge | Qgd | | 2.1 | _ | nC | | |
| Turn-On Delay Time | t _{D(ON)} | _ | 9.9 | _ | ns | | |
| Turn-On Rise Time | tR | | 24.5 | _ | ns | V _{DS} = 10V, I _D = 8.5A | |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 66.4 | _ | ns | $V_{GS} = 4.5V, R_{G} = 1.8\Omega$ | |
| Turn-Off Fall Time | tr | _ | 20.8 | | ns | <u> </u> | |

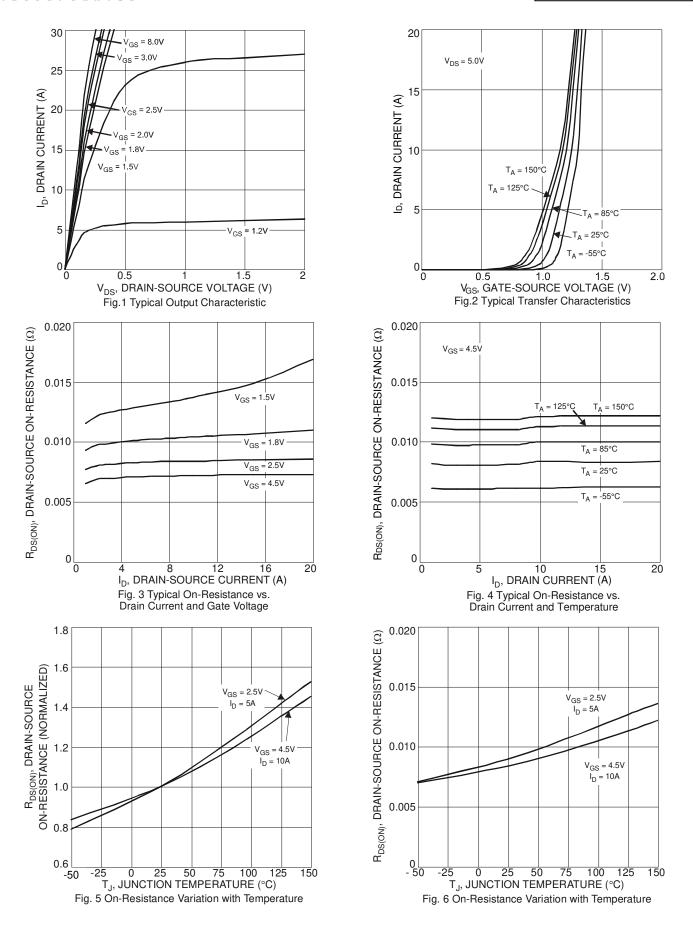
Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

^{6.} Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

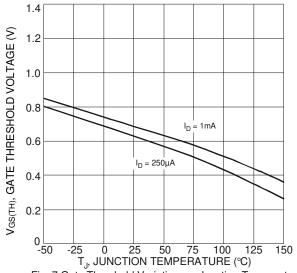
^{7.} Short duration pulse test used to minimize self-heating effect.

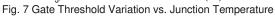
^{8.} Guaranteed by design. Not subject to production testing.

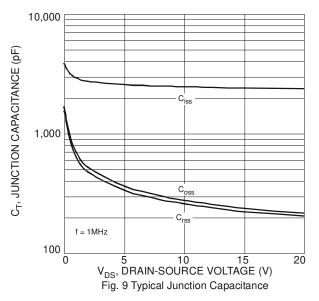


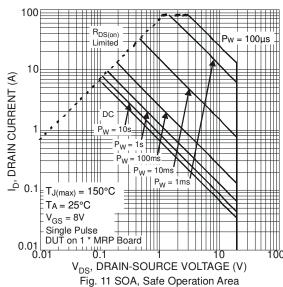


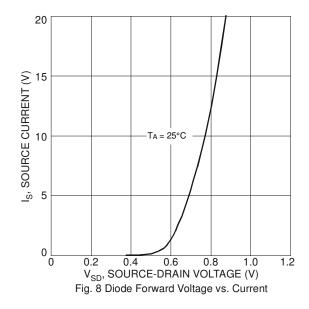


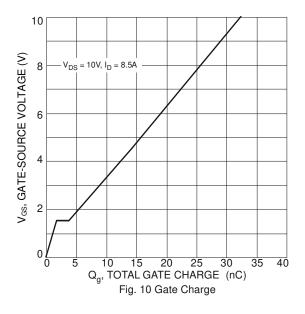




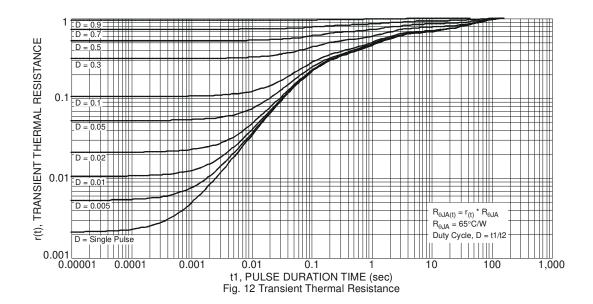










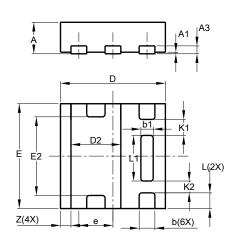




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type E)

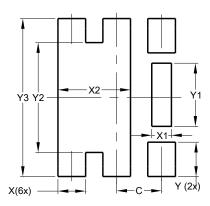


| | U-DFN2020-6 Type E | | | | | | | |
|-----|-----------------------|---------|-------|--|--|--|--|--|
| Dim | | | | | | | | |
| Α | 0.57 | 0.63 | 0.60 | | | | | |
| A1 | 0 | 0.05 | 0.03 | | | | | |
| A3 | _ | _ | 0.15 | | | | | |
| b | 0.25 | 0.35 | 0.30 | | | | | |
| b1 | 0.185 | 0.285 | 0.235 | | | | | |
| D | 1.95 | 2.05 | 2.00 | | | | | |
| D2 | 0.85 | 1.05 | 0.95 | | | | | |
| Е | 1.95 | 2.05 | 2.00 | | | | | |
| E2 | 1.40 | 1.60 | 1.50 | | | | | |
| е | _ | _ | 0.65 | | | | | |
| L | 0.25 | 0.35 | 0.30 | | | | | |
| L1 | 0.82 | 0.92 | 0.87 | | | | | |
| K1 | _ | _ | 0.305 | | | | | |
| K2 | _ | _ | 0.225 | | | | | |
| Z | - | _ | 0.20 | | | | | |
| All | Dimen | sions i | in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type E)



| Dimensions | Value (in mm) | | | |
|------------|------------------|--|--|--|
| С | 0.650 | | | |
| X | 0.400 | | | |
| X1 | 0.285 | | | |
| X2 | 1.050 | | | |
| Υ | 0.500 | | | |
| Y1 | 0.920 | | | |
| Y2 | 1.600 | | | |
| Y3 | 2.300 | | | |



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